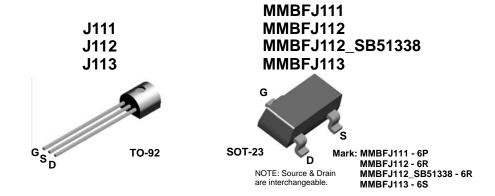


August 2012

J111 / J112 / J113 / MMBFJ111 / MMBFJ112 / MMBFJ112_SB51338 / MMBFJ113 N-Channel Switch

Features

- This device is designed for low level analog switching, sample and hold circuits and chopper stabilized amplifiers.
- · Sourced from Process 51.
- · Source & Drain are interchangeable.



Absolute Maximum Ratings* T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	35	V
V _{GS}	Gate-Source Voltage	-35	V
I_GF	Forward Gate Current	50	mA
T _{J,} T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired. **NOTES:**

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_a = 25^{\circ}$ C unless otherwise noted

Symbol	Parameter		Units	
		J111-113	*MMBFJ111-113	Oille
P _D	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{ heta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{ heta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

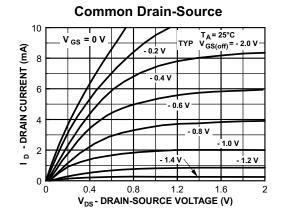
^{*} Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

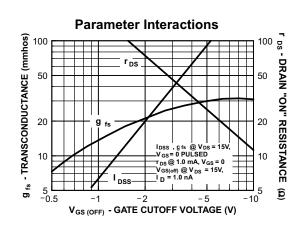
Electrical Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charac	Off Characteristics					
BV _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = -1.0 \mu A, V_{DS} = 0$	-35			V
I _{GSS}	Gate Reverse Current	V _{GS} = -15V, V _{DS} = 0			-1.0	nA
V _{GS(off)}	Gate-Source Cutoff Voltage	$V_{DS} = 5.0V, I_D = 1.0\mu A$ 111	-3.0		-10	V
		112	-1.0		-5.0	V
		MMBFJ112_SB51338	-3.0		-5.0	V
		113	-0.5		-3.0	V
I _{D(off)}	Drain Cutoff Leakage Current	$V_{DS} = 5.0V, V_{GS} = -10V$			1.0	nA
On Characteristics						
I _{DSS}	Zero-Gate Voltage Drain	$V_{DS} = 15V, I_{GS} = 0$ 111	20			mA
	Current*	112	5.0			mΑ
		113	2.0			mA
r _{DS(on)}	Drain-Source On Resistance	$V_{DS} \le 0.1 V, V_{GS} = 0$ 111			30	Ω
, ,		112			50	Ω
		113			100	Ω
Small Sign	nal Characteristics					
C _{dg(on)}	Drain Gate & Source Gate On	$V_{DS} = 0$, $V_{GS} = 0$, $f = 1.0MHz$			28	pF
C _{sg(on)}	Capacitance					
C _{dg(off)}	Drain-Gate Off Capacitance	$V_{DS} = 0$, $V_{GS} = -10V$, $f = 1.0MHz$			5.0	pF
C _{sg(off)}	Source-Gate Off Capacitance	$V_{DS} = 0$, $V_{GS} = -10V$, $f = 1.0MHz$			5.0	pF

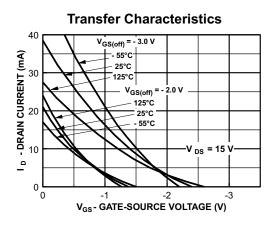
^{*} Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 3.0%

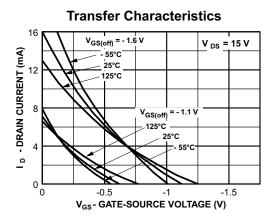
Typical Performance Characteristics

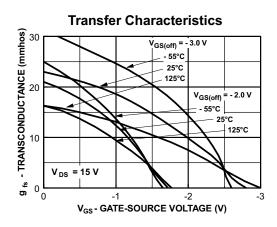


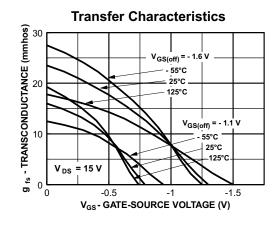


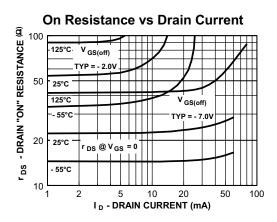
Typical Performance Characteristics (continued)

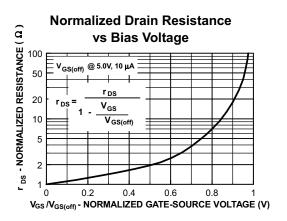




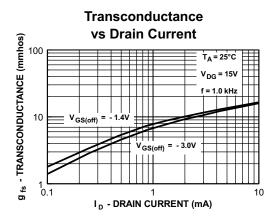


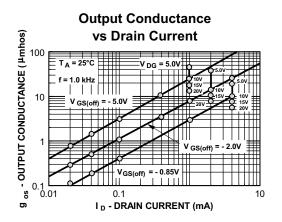


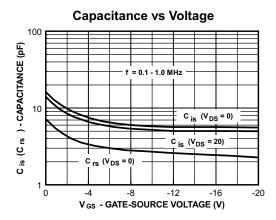


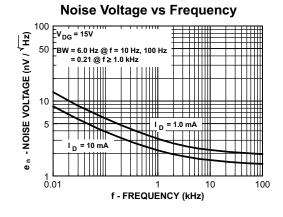


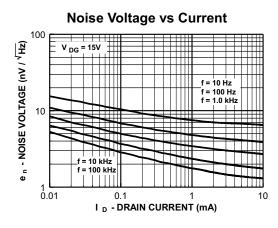
Typical Performance Characteristics (continued)

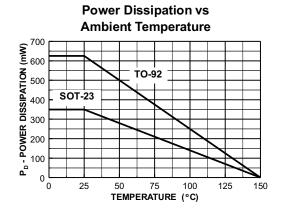






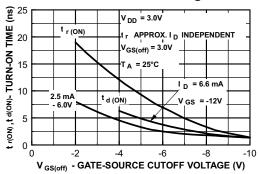




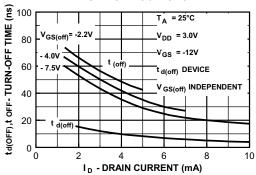


Typical Performance Characteristics (continued)

Switching Turn-On Time vs Gate-Source Voltage



Switching Turn-Off Time vs Drain Current





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Definition of Terms

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